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Theoretical Modeling and Analysis of Directional Spectrum Emissivity and Its Pattern for Random Rough Surfaces with a Matrix Method

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Abstract: The emissivity is an important surface property parameter in many fields, including infrared temperature measurement. In this research, a symmetry theoretical model of directional spectral emissivity prediction is proposed based on Gaussian random rough surface theory. A numerical solution based on a matrix method is determined based on its symmetrical characteristics. Influences of the index of refraction *n* and the root mean square (RMS) roughness σ_{rms} on the directional spectrum emissivity ε are analyzed and discussed. The results indicate that surfaces with higher *n* and lower σ_{rms} tend to have a peak in high viewing angles. On the contrary, surfaces with lower n and higher σ_{rms} tend to have a peak in low viewing angles. Experimental verifications based on infrared (IR) temperature measurement of Inconel 718 sandblasted surfaces were carried out. This model would contribute to understand random rough surfaces and their emitting properties in fields including machining, process controlling, remote sensing, etc.

Keywords: Inconel 718; surface integrity; Gaussian random rough surface; matrix method; infrared emissivity

1. Introduction

As a surface property parameter, the precise determination of emissivity is important in many fields, including infrared temperature measurement. Experimental studies have shown that the main factors affecting the emissivity of a given rough surface are the chemical composition [1], temperature [2–4], wavelength [2,3] and surface morphology [4,5], as shown in Figure 1. Closely related to the speed of light in the material, the index of refraction *n* depends mainly on the material, and is affected by temperature, wavelength and other factors. Surface morphology has an effect on reflection and shadowing, influencing the emissivity ε . In this paper, if not specifically indicated, the term emissivity refers to directional spectrum emissivity.



Figure 1. Factors affecting the emissivity ε of rough surfaces.



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Copyright: © 2021 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). The indirect influences of temperature, wavelength and other factors on emissivity can be experimentally measured and are relatively clear. Studies on Pt-10Rh and SiC indicate that the emissivity of rough surface increases with the increase of temperature and the decrease of wavelength [6]. Similar phenomena are found in difficult-to-process materials including Inconel 718 and Ti6Al4V [3,7–9]. Other factors including chemical composition [1], heat treatment [2,3] and oxidation [10,11] may also have an effect on emissivity. The influence of chemical composition and heat treatment are combined in the influence of the index of refraction *n*. The oxide layers are neglectable if not specifically oxidized.

The influence of surface morphology is complicated and not yet well understood. It is found that coarsely sandblasted samples, compared with finely sandblasted samples, have higher total hemispherical emissivity at low temperature, but lower emissivity in high temperature [12]. It is also reported that differently processed surfaces with close surface roughness Ra may have very different emissivities [13]. Further information is needed to understand this ambiguity.

Theoretical modelling studies have been carried out to predict the emissivity of rough surfaces. This was predicted considering the shadowing effect [14]. The surface was however assumed as a grey body, which limits its application. The average probability that infrared radiation emitted hits the surface directly was calculated, and the influence of reflection on emissivity of rough surfaces was estimated by Wen and Mudawar [15]. Reflectivity of the rough surface is also affected by viewing angle. Thus, errors were introduced in applying the average probability. Emissivity model of rough surfaces considering shadowing effect and reflection was established [16], while the reflection was assumed no more than once. Emissivity model of sea surfaces have been carried out by Wu and Smith [17] and Li et al. [18–21] respectively. However, sea surfaces have certain patterns (perpendicular to the wind), and are composed merely by sea water. Their models lack in generality.

Despite this valuable work, due to the complexity of the emission processes, the influences of the index of refraction *n* and surface morphology on the directional emissivity ε are to be further studied, especially the influence of the index of refraction *n*. In this research, influences of the index of refraction *n* and root mean square (RMS) roughness σ_{rms} on emissivity ε are modeled, as shown in Figure 1. Geometric optics are assumed and a directional spectral emissivity prediction model based on the Gaussian random rough surface is briefly analyzed, as similar models have already been proposed and derived in other fields [18,22]. Then, a novel matrix method was introduced, and sectional Romberg integral is applied, to numerically solve the proposed model. Influences of the index of refraction *n* and the root mean square (RMS) roughness σ_{rms} on the directional emissivity ε are analyzed and discussed. It is found that emissivity of surfaces with lower σ_{rms} and higher *n* tends to have a peak in high viewing angles. On the contrary, the emissivity of surfaces with higher σ_{rms} and lower *n* tends to have a peak in low viewing angles. Finally, experimental verification based on IR temperature measurement of an Inconel 718 machined surface is carried out.

2. Methodology

In the model part, the surface is assumed to be Gaussian, and limited to the area of geometrical optics (GO). According to the number of reflecting processes involved, the emissivity is divided into components. To contribute to one component, an infrared ray must experience processes including emission, shadowing and reflection. As the surface is random, each process can only be discussed statistically by a possibility density function, and each component calculated by integration. The expression of emissivity is derived by summarizing the components. In this part, it is noticed that the emission, shadowing and reflection processes have no inner connection, and can be expressed separately. Similar processes of different components share the same properties, and can be depicted by one formula.

The expression of emissivity is too complex to be solved analytically. In the numerical solution part, considering the discoveries above, a matrix method is designed. Emission, shadowing and reflection processes are represented and computed by matrixes. Nested loops are avoided and computational time is shortened.

Experimental verification based on IR temperature measurement of an Inconel 718 machined surface is carried out. Temperature and emissive power are measured simultaneously to calculate the emissivity. Other experimental studies are also cited to further verify the model. The framework of this paper is displayed in Figure 2.



Figure 2. The framework of this paper.

3. Modeling of Directional Emissivity of Rough Surfaces

3.1. Analysis of Emissivity of Rough Surfaces

To predict the emissivity of rough surfaces, three-dimensional Gaussian random rough surface is assumed, as shown in Figure 3. The three-dimensional Gaussian random rough surface is generated by a stationary stochastic process, as expressed by Equation (1) [22]:

$$\langle \zeta(\mathbf{r}) \rangle = 0 \tag{1}$$

$$\zeta(\mathbf{r})\zeta(\mathbf{r}')\rangle = \sigma_{rms}^2 \cdot e^{\frac{-(x_1 - x_2)^2 - (y_1 - y_2)^2}{2\sigma_{rms}^2}}$$
(2)

where *r* is the position vector, and *x*, *y*, *z* are the coordinates of *r*. We have:

$$t_N(p,q,\sigma_{rms}) = \frac{1}{2\pi\sigma_{rms}^2} \cdot e^{\frac{-p^2 - q^2}{2\sigma_{rms}^2}}$$
(3)

where *p*, *q* are the slopes of the surface in *x*, *y* direction, respectively. t_N (*p*, *q*, σ_{rms}) is the probability density function of *p*, *q*. The Gaussian random rough surfaces have the following characteristics:

- The surface is isotropic (and statistically symmetry);
- *p* and *q* are randomly distributed according to a Gaussian distribution;
- No correlation between *p* and *q*.



Figure 3. Effect of surface morphology on emissivity. (**a**): Gaussian random rough surface (Ref. [23], Figure 2) (**b**): Fresnel's law. (**c**): Reflection enhancement.

In this study, emissivity is defined as the emissive power of the rough surface compared with a black body, and geometric optics is assumed. According to Fresnel's law and the reflection law:

$$\varepsilon_F(n,\theta_s) = \begin{cases} \frac{\sqrt{n^2 - \sin^2(\theta_s)}}{n^2 \cos(\theta_s) + \sqrt{n^2 - \sin^2(\theta_s)}} + \frac{\cos(\theta_s)}{\cos(\theta_s) + \sqrt{n^2 - \sin^2(\theta_s)}}, & \tan\theta_s < n\\ \frac{n^2 \cos(\theta_s)}{n^2 \cos(\theta_s) + \sqrt{n^2 - \sin^2(\theta_s)}} + \frac{\cos(\theta_s)}{\cos(\theta_s) + \sqrt{n^2 - \sin^2(\theta_s)}}, & \tan\theta_s \ge n \end{cases}$$
(4)

where ε_F is emissivity, *n* is the index of refraction, θ_S is the viewing angle.

The main phenomena in the emission process of rough surfaces are Fresnel's law and reflection enhancement. Figure 3b shows that the smooth surface consists of many horizontal microelements, while the rough surface consists of elements with varied directions, each having different emissivity in the same direction. Reflection enhancement refers to the phenomenon whereby reflection induces higher emissivity near the normal direction in rough surfaces, as depicted in Figure 3c. Reflection enhancement may also cause lower emissivity in high viewing angles. Due to their combined effect, the influence of surface morphology is complicated and not yet well understood.

3.2. Modelling of Emissivity of Rough Surfaces

Directional spectral emissivity refers to the ability of measured surface to emit in a certain wavelength and direction compared with a black body. A statistical model is established to calculate the emissivity of rough surfaces.

Infrared radiation emitted by an element may leave the surface directly (zeroth-order), reflect once (first-order), twice (second-order), and so on. Considering that the correlation between emissivity and the emitted power is linear, the emissivity could be divided into different order components, and the components can be computed separately. Components of second order and above are called high-order components collectively, as presented in Equation (5):

$$\varepsilon = \sum_{i=0}^{\infty} \varepsilon_i \tag{5}$$

Zeroth-order component refers to emissivity related to infrared radiation that leaves the surface directly. To contribute to zeroth-order component, an infrared ray must be emitted, and not be blocked by another part of the surface. Different elements have different directions, and thus have different local viewing angle θ_l , as illustrated in Figure 4b. According to Equation (4), their local emissivities ε_l are not equal. The emitted radiation ray may also be blocked by another element, and the possibility is a function of its slope.



Figure 4. Zeroth-order component (a): Element. (b): Projection of the element.

In Figure 4a:

$$\eta = \left(\frac{-p}{\sqrt{p^2 + q^2 + 1}}, \frac{-q}{\sqrt{p^2 + q^2 + 1}}, \frac{1}{\sqrt{p^2 + q^2 + 1}}\right) \tag{6}$$

where η is the normal direction of the element. As shown in Figure 4b, projection of the element distorts depending on η and the viewing direction Ω_S . Thus, area projection coefficient A_p is:

$$A_{p} = \begin{cases} \eta_{yoz} \cdot \mathbf{\Omega}_{s} = \cos(\theta_{s}) - q\sin(\theta_{s}), & q < \cot(\theta_{s}) \\ 0, & q \ge \cot(\theta_{s}) \end{cases}$$
(7)

where η_{yoz} is the component of η in plane *yoz*.

$$t(\theta_s, p, q, \sigma_{rms}) = \frac{A_p \cdot e^{\frac{-p-q}{2\sigma_{rms}^2}}}{\int_{-\infty}^{\cot\theta_s} \int_{-\infty}^{\infty} A_p \cdot e^{\frac{-p^2-q^2}{2\sigma_{rms}^2}} dpdq}, \quad (q < \cot\theta_s)$$
(8)

where *t* (θ_s , *p*, *q*, σ_{rms}) is the possibility that the slope of the emitting element is *p*, *q*. Smith's shadowing function *S*(θ_s , σ_{rms}) [24,25] is the possibility that infrared radiation is

$$S(\theta_s, \sigma_{rms}) == \begin{cases} \frac{1}{\Lambda(\theta_s, \sigma_{rms})+1}, & \theta_s < \frac{\pi}{2} \\ 0, & \theta_s \ge \frac{\pi}{2} \end{cases}$$
(9)

$$\Lambda(\theta_s, \sigma_{rms}) = \frac{1}{2} \sqrt{\frac{2}{\pi}} \cdot \frac{\sigma_{rms}}{\cot \theta_s} e^{-\frac{\cot^2 \theta_s}{2\sigma_{rms}}} - \operatorname{erfc}\left(\frac{\cot \theta_s}{\sqrt{2}\sigma_{rms}}\right)$$
(10)

$$\varepsilon_{l}(n, p, q, \theta_{s}) = \begin{cases} \frac{\sqrt{n^{2} - \sin^{2}(\theta_{sl})}}{n^{2}\cos(\theta_{sl}) + \sqrt{n^{2} - \sin^{2}(\theta_{sl})}} + \frac{\cos(\theta_{sl})}{\cos(\theta_{sl}) + \sqrt{n^{2} - \sin^{2}(\theta_{sl})}}, & \tan\theta_{sl} < n\\ \frac{n^{2}\cos(\theta_{sl})}{n^{2}\cos(\theta_{sl}) + \sqrt{n^{2} - \sin^{2}(\theta_{sl})}} + \frac{\cos(\theta_{sl}) + \sqrt{n^{2} - \sin^{2}(\theta_{sl})}}{\cos(\theta_{sl}) + \sqrt{n^{2} - \sin^{2}(\theta_{sl})}}, & \tan\theta_{sl} \ge n \end{cases}$$
(11)

$$\theta_{sl}(\theta_s, p, q) = \cos^{-1}\left(\frac{\cos(\theta_s) - q\sin(\theta_s)}{\sqrt{1 + p^2 + q^2}}\right)$$
(12)

The zeroth-order component is,

$$\varepsilon_{0} = \int_{-\infty}^{\cot\theta_{s}} \int_{-\infty}^{\infty} t(\theta_{s}, p, q, \sigma_{rms}) S(\theta_{s}, \sigma_{rms}) \varepsilon_{l}(n, p, q, \theta_{s}) dp dq$$
(13)

In Equation (13), we note that $S(\theta_s, \sigma_{rms})$ is not a function of p, q. The integration part depicts the emission process, while $S(\theta_s, \sigma_{rms})$ stands for not being blocked.

The first-order component refers to emissivity related to infrared radiation that reflects once before leaving the surface. To contribute to a zeroth-order component, an infrared ray must be emitted, hit another part of the surface, be reflected, and not hit the surface again. The process could be divided into two parts: emission and blocking, reflection and exiting. Figure 5 shows that the infrared radiation emitted by the first element hits the second element in direction Ω_1 , and the reflected beam leaves the surface in direction Ω_S . By applying the local coordinate system x'y'z', the emission process is similar to the zeroth-order component.



Figure 5. First-order component.

According to the reflection law [28]:

$$\eta = \frac{\mathbf{\Omega}_s - \mathbf{\Omega}_1}{|\mathbf{\Omega}_s - \mathbf{\Omega}_1|} \tag{14}$$

which is:

$$p = \frac{\sin \theta_1 \sin \phi_1}{\cos \theta_s - \cos \theta_1} \tag{15}$$

$$q = \frac{\sin\theta_1 \cos\phi_1 - \sin\theta_s}{\cos\theta_s - \cos\theta_1} \tag{16}$$

By substituting Equations (11) and (12) into Equations (7) and (8), $t(\theta_1, p, q, \sigma_{rms})$ and $\varepsilon_l(n, p, q, \theta_s)$ could be expressed as $t(\theta_s, \theta_1, \phi_1, \sigma_{rms})$ and $\varepsilon_l(n, \theta_1, \phi_1, \theta_s)$. According to Kirchhoff's law we have [28]:

$$\rho = 1 - \alpha = 1 - \varepsilon_l \tag{17}$$

where α , ρ are the absorptivity and reflectivity, respectively. Noting that Gaussian random rough surface is isotropic and statistically symmetry, we have:

$$\varepsilon_1 = \int_0^{2\pi} \int_0^{\pi-\theta_s} i(\theta_1, \sigma_{rms}) t(\theta_s, \theta_1, \phi_1, \sigma_{rms}) S(\theta_s, \sigma_{rms}) [1 - \varepsilon_l(n, \theta_1, \phi_1, \theta_s)] \cdot \sin\theta_1 d\theta_1 d\phi_1$$
(18)

$$i(\theta_1, \sigma_{rms}) = \int_{-\infty}^{\cot\theta_1} \int_{-\infty}^{\infty} t(\theta_1, p_1, q_1, \sigma_{rms}) [1 - S(\theta_1, \sigma_{rms})] \varepsilon_l(n, \theta_1, \phi_1, \theta_s) dp_1 dq_1$$
(19)

where Equation (18) refers to the reflection process, and Equation (19) refers to the emitting process. Noting that $S(\theta_s, \sigma_{rms})$ is not a function of p, q. Equation (13b) is mainly about emission and blocking, while Equation (18) is about reflection and exiting. In Equation (19), the integration part depicts the emission process, while $[1 - S(\theta_s, \sigma_{rms})]$ stands for blocking, which is similar to Equation (13). In Equation (19), $S(\theta_s, \sigma_{rms})$ stands for exiting, and the rest for reflection.

As shown in Figure 6, second-order component refers to emissivity related to infrared radiation that reflects twice before leaving the surface. By applying a local coordinate system to the first element and the second element, we have:

$$\varepsilon_2 = \int_0^{2\pi} \int_0^{\pi-\theta_s} i_2(\theta_2, \sigma_{rms}) t(\theta_s, \theta_2, \phi_2, \sigma_{rms}) S(\theta_s, \sigma_{rms}) [1 - \varepsilon_l(n, \theta_2, \phi_1)] \cdot \sin\theta_2 d\theta_2 d\phi_2$$
(20)

$$i_{2}(\theta_{2},\sigma_{rms}) = \int_{-\infty}^{\cot\theta_{2}} \int_{-\infty}^{\infty} i_{1}(\theta_{1},\sigma_{rms})t(\theta_{s},\theta_{1},\phi_{1},\sigma_{rms}) \left[1 - S(\theta_{s},\sigma_{rms})\right] \left[1 - \varepsilon_{l}(n,\theta_{1},\phi_{1})\right] \cdot \sin\theta_{1}d\theta_{1}d\phi_{1}$$
(21)

$$i_{1}(\theta_{1},\sigma_{rms}) = \int_{-\infty}^{\cot\theta_{1}} \int_{-\infty}^{\infty} t(\theta_{1},p_{1},q_{1},\sigma_{rms}) [1-s(\theta_{1},\sigma_{rms})] \varepsilon_{l}(n,p_{1},q_{1}) dp_{1} dq_{1}$$
(22)



Figure 6. Second-order component.

Third order component and above are modeled similarly. We note that emissivity is not a function of φ and the model is symmetrical.

4. Numerical Solution Based on a Matrix Method

The directional spectral emissivity of the rough surfaces is too complex to be solved analytically. Generally, multiple integrals are computed by nested loops, and the operation period of nested loops increases exponentially with multiplicity. In this section, a novel matrix method is introduced, and sectional Romberg integral is applied to obtain numerical solutions quickly and precisely.

As shown in Section 3.2, high-order components are related to two basic process, emission and refraction. As mentioned in Section 3.1, a Gaussian random rough surface is isotropic (and symmetrical), and no correlation between p and q is assumed. From another point of view, the optics processes involved are emission, reflection and shadowing. Thus,

these processes can be represented by irrelevant matrixes. The numerical integration could be obtained by multiplying matrixes, which is much quicker than nested loops. We define:

$$Der(n) = Emi \cdot \left[(1 - S) \cdot Rbg_2 \cdot rft \right]^n$$
(23)

where Der(n) is the *n*-th order emissivity in the viewing angle θ_{s_k} . *Emi* is the emission matrix. *S* is the shadowing matrix. *Rbg*₂ is the Romberg matrix. Definitions of *Rbg*₂ and theoretical verification of the matrix method are presented in Appendix A. *rft* is the reflection matrix. This gives:

$$Emi = \begin{bmatrix} emi_1 & emi_2 & emi_3 & \dots & emi_{97} \end{bmatrix}$$
(24)

$$emi_{k} = \int_{-\infty}^{\cot\theta_{s_{k}}} \int_{-\infty}^{\infty} t(\theta_{s_{k}}, p, q, \sigma_{rms}) \varepsilon_{F}(n, p, q) dp dq$$
(25)

where θ_{s_k} are, respectively.

$$S = [S(\theta_{s_1}, \sigma_{rms}) \ S(\theta_{s_2}, \sigma_{rms}) \ S(\theta_3, \sigma_{rms}) \ \dots \ S(\theta_{s_{97}}, \sigma_{rms})]$$
(26)

$$rft = \begin{bmatrix} rft_{11} & rft_{12} & \dots & rft_{197} \\ rft_{21} & rft_{22} & \dots & rft_{2}97 \\ \vdots & \vdots & \ddots & \vdots \\ rft_{971} & rft_{972} & \dots & rft_{9797} \end{bmatrix}$$
(27)

$$rft_{lk} = (\pi - \theta_{s_k}) \cdot \int_0^{2\pi} t(\theta_{s_k}, \theta_l, \phi, \sigma_{rms}) [1 - \varepsilon_l(n, \theta_l, \phi)] \cdot \sin \theta_l d\phi$$
(28)

From the viewpoint of optics, as sketched in Figure 7, *Emi*, (1 - S), *Rbg*₂, *rft* are defined, representing the emission, shadowing, reflection and leaving processes, respectively. *emi*_k is the average emissivity of a random element in direction θ_K . Elements of (1 - S) are the possibility that a ray in direction θ_K hits the surface again. *Rbg*₂ is a constant matrix introduced by Romberg integration. *Rft*_{lk} is the average energy reflected to direction θ_K when a ray from direction θ_l hits a random element. Thus, the infrared rays are traced statistically by a matrix method.



Figure 7. Matrix method, in the viewpoint of optics.

Multiple integrations are generally computed by nested loops, in which t (θ_S , p, q, σ_{rms}) and ε_F (n, p, q) must be calculated repeatedly in every step of every integration. Thus, computational time increases exponentially with the order n. In matrix method, they are computed only in obtaining the matrixes. Therefore, the computational time hardly increases when n > 0. The amount of calculation is presented in Table 1. Table 2 illustrates that the estimated error of the matrix method is acceptable. Estimation of the error is summarized in Appendix A.

Approach	ε_0	ε_1	ε2	E3	ε_4
nested loops matrix method	$2.62 \cdot 10^{5}$ a $2.62 \cdot 10^{5}$	$3.82 \cdot 10^9$ $4.77 \cdot 10^8$	$\begin{array}{c} 8.00 \cdot 10^{12} \\ 4.77 \cdot 10^8 \end{array}$	$\frac{1.64 \cdot 10^{16}}{4.77 \cdot 10^8}$	3.36·10 ¹⁹ 4.77·10 ⁸
^a The results are counted by	MATLAB progra	m, when $h_{\theta} = 1/2$	$'128 \approx 0.008, h_p =$	$\pi/32 \approx 0.1, \theta_S =$	$= 20^{\circ}, \sigma_{rms} = 0.33.$

Table 1. How many times t (θ_S , p, q, σ_{rms}) and ε_F (n, p, q) are calculated in nested loops and matrix method.

Table 2. The influence of *n* and σ_{rms} on estimated error.

Index of Refraction <i>n</i>	RMS Roughness σ_{rms}					
	0	0.2	0.5	1	2	
1	$2 \cdot 10^{-9} a$	$3.55 \cdot 10^{-5}$	$8.00 \cdot 10^{-5}$	$6.23 \cdot 10^{-6}$	$5.65 \cdot 10^{-6}$	
2	$3.18 \cdot 10^{-6}$	$1.22 \cdot 10^{-4}$	$2.33 \cdot 10^{-4}$	$1.80 \cdot 10^{-4}$	$2.78 \cdot 10^{-4}$	
4	$1.86 \cdot 10^{-6}$	$2.43 \cdot 10^{-4}$	$1.65 \cdot 10^{-4}$	$1.15 \cdot 10^{-4}$	$1.21 \cdot 10^{-4}$	
8	$1.38 \cdot 10^{-6}$	$4.13 \cdot 10^{-4}$	$1.80 \cdot 10^{-4}$	$2.10 \cdot 10^{-4}$	$1.26 \cdot 10^{-4}$	
16	$4.59 \cdot 10^{-6}$	$2.75 \cdot 10^{-4}$	$3.10 \cdot 10^{-4}$	$3.54 \cdot 10^{-4}$	$3.34 \cdot 10^{-4}$	

^a Accuracy of the PC in this research is 2^{-30} (about 10^{-9}). Thus, this data has only one significant figure.

5. Results and Discussion

The effects of the index of refraction *n* and the RMS roughness σ_{rms} on the emissivity ε are discussed by setting different parameters. The numerical integral was carried out with the MATLAB R2018a program, using a personal computer running with an Intel Core I7-4720HQ, 3.6 GHz. CPU. In industry, *n* is mostly between 2 and 16, σ_{rms} is mostly under 1. The values of *n* and σ_{rms} is chosen inside this range by proportional sequences, to cover the majority of rough surfaces encountered in industry.

5.1. Pattern of Different Components

The patterns of different components are discussed. Figure 8 displays that higher order components are considerably smaller in scale. The proportion of higher order components increases with increasing σ_{rms} . The components of first order and above are almost 0 when the surface is smooth, and consists of only about 20% when the surface is relatively rough.

5.2. Effects of the Index of Refraction n on Emissivity ε

The index of refraction n depends on the chemical composition of the surface and varies with wavelength and temperature [28].

When the RMS roughness σ_{rms} is relatively high, ε would be dominated by σ_{rms} , which is to be discussed in Section 5.3. When σ_{rms} is relatively low, p, q converge to zero, and the surface would be too smooth for an infrared ray emitted to hit the surface again. Thus, ε depends mainly on ε_0 , and $\varepsilon_l \approx \varepsilon_F$. Equation (6) could be transformed into the following form:

$$\varepsilon_0 = S(\theta_s, \sigma_{rms}) emi(\theta_s, n, \sigma_{rms})$$
⁽²⁹⁾

$$emi(\theta_s, n, \sigma_{rms}) = \int_{-\infty}^{\cot \theta_s} \int_{-\infty}^{\infty} t(\theta_s, p, q, \sigma_{rms}) \varepsilon_l(n, p, q, \theta_s) dp dq$$
(30)

The patterns shown in Figure 9b are reported in experimental studies [14,29]. It is shown in Figure 9 that ε_F and ε have similar patterns. Obviously, *n* affects ε_l ($\varepsilon_l \approx \varepsilon_F$), and thus have an effect on ε . In another word, *n* influences ε_l by influencing the emission characteristics of the elements. *emi* (θ_S , *n*, σ_{rms}) is the same function that stands for the emission process mentioned in Section 4. In Equation (4), it can be analytically demonstrated that the extreme point is the polarizing angle, which is really interesting. Such a phenomenon could be valuable for further research.



Figure 8. Components of emissivity (a): n = 4, $\sigma_{rms} = 0.3$; (b): n = 4, $\sigma_{rms} = 0.5$; (c): n = 4, $\sigma_{rms} = 1$.



Figure 9. Comparison of the emissivity of elements and surfaces ($\sigma_{rms} = 0.1$). (a): Effect of the index of refraction *n* on emissivity of the elements ε_F . (b): Effect of *n* on emissivity of the surface ε .

5.3. Effects of RMS Roughness σ_{rms} on Emissivity ε

Referring to the root mean square of the slope of the surface elements, RMS roughness σ_{rms} is a surface integrity parameter. According to Equations (29) and (30), σ_{rms} affects both $S(\theta_S, \sigma_{rms})$ and $emi(\theta_S, n, \sigma_{rms})$. That is, σ_{rms} effects both of emission and shadowing. ε decreases with increasing σ_{rms} in high viewing angle, increases with increasing σ_{rms} in middle viewing angle, and first increases then decreases with increasing σ_{rms} in low viewing angle (near normal direction). Surfaces with very high σ_{rms} may have a peak in

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low viewing angle. It should be noted that high, middle and low here are a relative concept. As higher order components are relatively small, reflection is not discussed in details here.

As shown in Figure 10, on the one hand, the shadowing effect becomes more notable with increasing σ_{rms} . Figure 10a shows that $S(\theta_S, \sigma_{rms})$ decreases with increasing σ_{rms} in high viewing angle. Thus, ε decreases with increasing σ_{rms} in high viewing angle. On the other hand, these blocked infrared rays are redistributed in all directions, including middle viewing angles. Thus, ε increases with increasing σ_{rms} in middle viewing angle.



Figure 10. Effect of RMS roughness σ_{rms} on emitting process. (a): Effect on shadowing function *S* (θ_S , σ_{rms}). (b): Effect on ε when n = 8. (c): Effect on ε when n = 1.5.

On the other hand, *emi* (θ_S , *n*, σ_{rms}) varies with increasing σ_{rms} . Local emissivity of the elements ε_F (θ_S , *n*) are not a function of σ_{rms} , but the distribution of the elements can be influenced by σ_{rms} . Thus, σ_{rms} have an effect on the emissivity ε . As shown in Figure 11, *emi* (θ_S , *n*, σ_{rms}) could be considered as a convolution of ε_F (θ_S , *n*). Thus, the curve is flattened and the emissivity decreases with increasing σ_{rms} in high viewing angles, and increases with increasing σ_{rms} in middle viewing angles. The emissivity ε is dominated by σ_{rms} , and *n* have little effect on ε , as mentioned in Section 5.2. Similar patterns are reported experimentally [13,20].



Figure 11. Effect of RMS roughness σ_{rms} on emitting process and emissivity ε .

Near normal direction, the effect of σ_{rms} in middle viewing angle still works, and ε increase with increasing σ_{rms} firstly. While σ_{rms} is very high, $2 \cdot \sigma_{rms}$ may proceed the polarizing angle, where ε_F starts to decrease with increasing θ_S . Thus, ε near normal direction may decrease with increasing σ_{rms} . Due to this phenomenon near normal direction, surfaces with very high σ_{rms} tend to have a peak in low viewing angles.

5.4. Combined Effect of n and σ_{rms} on ε

Influences of the index of refraction *n* and root mean square (RMS) roughness σ_{rms} on emissivity ε are discussed based on Sections 5.2 and 5.3. *n* have an impact on *emi* (θ_S , *n*, σ_{rms}) by ε_F , and thus influences ε . σ_{rms} influences both *emi* (θ_S , *n*, σ_{rms}) and *S* (θ_S , σ_{rms}). In optics point of view, *n* influences primarily emission process, while σ_{rms} influences both emission and shadowing, as shown in Figure 12.



Figure 12. Mechanism of the influence of the index of refraction *n* and RMS roughness σ_{rms} on emissivity ε .

When σ_{rms} is relatively high, ε is dominated by σ_{rms} . It is found that ε decreases with increasing σ_{rms} in high viewing angle, increases with increasing σ_{rms} in middle viewing angle, and first increases then decreases with increasing σ_{rms} near normal direction. Therefore, surfaces with very high σ_{rms} may have a peak in low viewing angle. When σ_{rms} is relatively low, ε tend to decrease with increasing n, and have a steeper peak in high viewing angles. The extreme point is the Brewster's angle, which increases with increasing n.

Summarizing the conclusions above, surfaces can be divided into three areas depending on index of refraction *n* and RMS roughness σ_{rms} . Surfaces with lower σ_{rms} and higher *n* tends to have a peak in high viewing angles [30–32]. On the contrary, surfaces with higher σ_{rms} and lower *n* tends to have a peak in low viewing angles. There is an intermediate region between the two areas [29,32], as shown in Figure 13.



Figure 13. Influence of the index of refraction *n* and RMS roughness σ_{rms} on the pattern of emissivity.

6. Verification by Simulated Experiment

According to Plunk's law:

$$E(\lambda, T) = \varepsilon \frac{C_1 \lambda^{-5}}{e^{\frac{C_2}{\lambda T}} - 1}$$
(31)

where $C_1 \approx 3.7418 \cdot 10^{-16} \text{ W} \cdot \text{m}^2$, $C_2 \approx 1.4388 \cdot 10^{-2} \text{ m} \cdot \text{K}$.

Thus, the emissivity of the surface could be calculated by measuring the temperature *T* and the emissive power *E* (λ , *T*). Figure 14a depicts the principle of the proposed verification experiment. The temperature *T* of the sample is measured by thermocouples. The emissive powe *E* (λ , *T*) is measured by an IR thermometer from different directions. All data is imported to a personal computer, by which the emissivity ε is calculated according to Equation (31). All samples are heated to one same temperature (900 K), in order to minimize the error.



Figure 14. Experimental setup of IR temperature measurement. (**a**): Principle of the measurement. (**b**): The sample in Figure 14a. (**c**): The equipment and sample involved in Figure 14a.

As shown in Figure 14b, the samples introduced are polished Inconel 718 columns, ϕ 27 × 18 mm, with a blind hole drilled to place the thermocouple. Inconel 718 is a difficult-to-process material. The surface roughness of the samples were Ra 0.17 ± 0.009 µm, and the RMS roughness were 1.16 ± 0.05. State and properties of the sample were referred in [33]. As shown in Figure 14c, the temperature values of the samples were measured by a DAQ-2401 thermometer (OMEGA, city, state abbrev if USA, country) equipped with a type-K thermocouple.

The emissive power $E(\lambda, T)$ was measured by the IR thermometer. The wavelength of the IR thermometer is 1.7 µm. Further information was reported by Zhao [34] et al. The upper surface of the sample was heated to 900 K to minimum the environmental interference. Five points in one sample are chosen for each group in the experimental study. As shown in Figure 15, the experimental results match well with the model.



Figure 15. Comparison between experimental and theoretical results (index of refraction n = 4.34).

Sandblasted surfaces have similar pattern with Gaussian random rough surface. Emissivity of Inconel 718 sandblasted surfaces were reported by Campo [35] et al. Figure 16 shows that the experimental results match well with the theoretical results. Deviations at higher viewing angles might due to diffraction.



Figure 16. Experimental and theoretical results of smooth surface (Where RMS roughness $\sigma_{rms} = 0.35$, index of refraction n = 2.85, 3.35, 4.0, 4.8, 5.8, 7.2, respectively).

7. Conclusions

In this research, a theoretical model considering the index of refraction n and the root mean square (RMS) roughness σ_{rms} is established out to predict the emissivity ε of rough surfaces. The directional spectral emissivity prediction model based on the Gaussian random rough surface is proposed. Then, the sectional Romberg integration based on a novel matrix method is applied to numerically solve the proposed model. Influences of the index of refraction n and the RMS roughness σ_{rms} on the emissivity ε are analyzed and discussed. Experimental verification is carried out with Inconel 718 samples. In this research, diffraction is neglected, and the differences between real [36] and Gaussian rough surface are also neglected. Their potential effects on emissivity are to be further researched. The main conclusions drawn from this work are as follows:

- (1) A directional spectral emissivity prediction model of rough surfaces is established considering the shadowing effect and the reflection enhancement. Sectional Romberg integration based on a novel matrix method is applied to numerically solve the proposed model and is theoretically verified. The computational time of the matrix method is compared with that of the traditional method. Errors induced in the matrix method are estimated.
- (2) The influence of the index of refraction *n* and RMS roughness σ_{rms} on the emissivity ε is discussed according to the model. It is found that higher order components are smaller in scale and their energy is more concentrated near the normal direction.

- (3) *n* influences ε by influencing ε_F (or from an optics point of view, the emission process). When σ_{rms} is relatively low, ε tends to decrease with increasing *n*, and have a steeper peak in high viewing angles. The extreme point is the Brewster's angle, which increases with increasing *n*. When the RMS roughness σ_{rms} is relatively high, ε would be dominated by σ_{rms} , and influence of *n* would be quenched.
- (4) σ_{rms} influences both $S(\theta_S, \sigma_{rms})$ and $emi(\theta_S, n, \sigma_{rms})$ (both emitting and shadowing). That is, σ_{rms} effects both of emitting and shadowing. ε decreases with increasing σ_{rms} in high viewing angle, increases with increasing σ_{rms} in middle viewing angle, and first increases then decreases with increasing σ_{rms} near normal direction. Surfaces with very high σ_{rms} may have a peak in low viewing angle.
- (5) Surface with lower σ_{rms} and higher *n*, due to Fresnel's law, tends to have a peak in high viewing angles. On the contrary, surface with higher σ_{rms} and lower *n*, mainly due to reflection enhancement, tends to have a peak in low viewing angles. In the intermediate region, due to their combined effect, the emissivity has no recognizable peak and decreases with increasing viewing angle.

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Appendix A

As a variable step-size integration method, Romberg integration is fast to converge and reliable in complex integration. It is defined as follows:

$$T_n = \frac{h}{2} \left[f(a) + f(b) + 2\sum_{k=1}^{n-1} f(x_k) \right]$$
(A1a)

$$S_n = T_{2n} + \frac{1}{3}(T_{2n} - T_n)$$
(A1b)

$$C_n = S_{2n} + \frac{1}{15}(S_{2n} - S_n) \tag{A1c}$$

$$R_n = C_{2n} + \frac{1}{3}(C_{2n} - C_n)$$
(A1d)

where *h* is the step-size, and x_K are values of *x* at the bisection points of the integration interval. Thus, x_1 , x_{17} are the upper and lower limit of integration, respectively. R_n is the Romberg integration. T_n , S_n , C_n are trapezoidal, Simpson and Cotes integration, respectively. Its error is estimated as:

$$e_{R_{2n}} = |R_{2n} - R_n| \tag{A1e}$$

In this study, the integration region is $(-\pi, \pi)$. In order to gain better accuracy, the region is divided into six equal segments. *n* is set as 2. In the first segment, which is $(-\pi, -2\pi/3)$, according to Equation (A1a) to Equation (A1d), we have:

$$\int_{x_1}^{x_{17}} f(x) dx \approx R_2 = \frac{x_{17} - x_1}{11,340} (217x_1 + 1024x_2 + 352x_3 + 1024x_4 + 436x_5 + 1024x_6 + 352x_7 + 1024x_8 + 434x_9 + 1024x_{10} + 352x_{11} + 1024x_{12} + 436x_{13} + 1024x_{14} + 352x_{15} + 1024x_{16} + 217x_{17})$$
(A2a)

$$\int_{x_1}^{x_{17}} f(x) dx \approx R_1 = \frac{x_{17} - x_1}{5670} (217x_1 + 1024x_3 + 352x_5 + 1024x_7 + 436x_9 + 1024x_{11} + 352x_{13} + 1024x_{15} + 217x_{17})$$
(A2b)

Define:

$$Rbg'_{2} = \frac{x_{17} - x_{1}}{11,340} \begin{bmatrix} 217 & 1024 & 352 & 1024 & 436 & 1024 & 352 & 1024 \\ 434 & 1024 & 352 & 1024 & 436 & 1024 & 352 & 1024 & 217 \end{bmatrix}$$
(A3a)

$$Rbg'_{1} = \frac{x_{17} - x_{1}}{5670} \begin{bmatrix} 217 & 0 & 1024 & 0 & 352 & 0 & 1024 & 0 \\ 436 & 0 & 1024 & 0 & 352 & 0 & 1024 & 0 & 217 \end{bmatrix}$$
(A3b)

$$X' = \left[\begin{array}{cccc} x_1 & x_2 & x_3 & \dots & x_{17} \end{array} \right] \tag{A4}$$

thus:

$$Rbg'_{1} \cdot X' = R_{1} \approx \int_{x_{1}}^{x_{17}} f(x)dx$$
 (A5a)

$$Rbg'_{2} \cdot X' = R_{2} \approx \int_{x_{1}}^{x_{17}} f(x)dx$$
 (A5b)

In this study, sectional Romberg integration is imposed. We define:

$$Rbg_{2} = \frac{\pi}{3 \cdot 11,340} \begin{bmatrix} 217 & Rbg' & 434 & Rbg' & 434 & Rbg' \\ & 434 & Rbg' & 434 & Rbg' & 434 & Rbg' & 217 \end{bmatrix}$$
(A6a)

$$Rbg' = \begin{bmatrix} 1024 & 352 & 1024 & 436 & 1024 & 352 & 1024 \\ 434 & 1024 & 352 & 1024 & 436 & 1024 & 352 & 1024 \end{bmatrix}$$
(A6b)

$$Rbg_{1} = \frac{\pi}{3.11,340} \begin{bmatrix} 217 & Rbg'' & 434 & Rbg'' & 434 & Rbg'' \\ 434 & Rbg'' & 434 & Rbg'' & 434 & Rbg'' & 217 \end{bmatrix}$$
(A7a)

$$Rbg' = \begin{bmatrix} 0 & 1024 & 0 & 352 & 0 & 1024 & 0 \\ 436 & 0 & 1024 & 0 & 352 & 0 & 1024 & 0 \end{bmatrix}$$
(A7b)

$$X = \left[f(-\pi) \quad f\left(\frac{-47\pi}{48}\right) \quad f\left(\frac{-46\pi}{48}\right) \quad \dots \quad f\left(\frac{47\pi}{48}\right) \quad f(\pi) \right]$$
(A8)

then:

$$Rbg_2 \cdot X \approx \int_{-\pi}^{\pi} f(x)dx$$
 (A9a)

$$Rbg_1 \cdot X \approx \int_{-\pi}^{\pi} f(x)dx$$
 (A9b)

$$e_{R_2} = |Rbg_2 \cdot X - Rbg_1 \cdot X| \tag{A10}$$

noting that *S* (θ_S , σ_{rms}) is not a function of *p*, *q*, θ_1 , θ_2 or ϕ . Thus:

$$Der_{k}(0) = Emi \cdot S = \int_{-\infty}^{\cot \theta_{s}} \int_{-\infty}^{\infty} t(\theta_{s_{k}}, p, q, \sigma_{rms}) \varepsilon_{l}(n, p, q) s(\theta_{s_{k}}, \sigma_{rms}) dp dq \approx \varepsilon_{0}$$
(A11a)

$$Der_{k}(1) = Emi \cdot (1-S) \cdot Rbg_{2} \cdot rft \cdot S$$

$$= \int_{0}^{2\pi} \int_{0}^{\pi-\theta_{s}} t(\theta_{s}, \theta_{1}, \phi_{1}, \sigma_{rms}) S(\theta_{s}, \sigma_{rms}) [1 - \varepsilon_{l}(n, \theta_{1}, \phi_{1})] \cdot \sin \theta_{1} \qquad (A11b)$$

$$\cdot \int_{-\infty}^{\cot \theta_{1}} \int_{-\infty}^{\infty} t(\theta_{1}, p_{1}, q_{1}, \sigma_{rms}) [1 - S(\theta_{1}, \sigma_{rms})] \varepsilon_{l}(n, p_{1}, q_{1}) dp_{1} dq_{1} d\theta_{1} d\phi_{1} \approx \varepsilon_{1}$$

High-order components could be verified similarly. The error was estimated according to Equation (A10).

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